1.0 Abstract
A simple Application Program Interface (API) has been created to allow programmers of the M16C/62P (M30626FHP) and M16C/26 (M30262F8) to easily integrate reprogramming abilities into their applications using CPU Rewrite. CPU Rewrite is the term used to describe a Renesas MCU's ability to reprogram its own internal Flash memory while running in its normal operational mode.

2.0 Introduction
The M16C/62P and M16C/26 both use a flash technology referred to as HND. This Flash technology allows a user to program the internal flash memory of the MCU a WORD (16 bits) at a time. Since the flash technologies are the same, the source code for this API is virtually the same.

This API uses Erase-Write Mode 1 (or EW1 Mode) of CPU Rewrite. This mode allows the code responsible for erasing and programming to execute from flash memory as opposed to earlier MCUs that required the code to run from RAM when performing CPU Rewrite operations.

The API source files comply with Renesas’ NC30 compilers only.

3.0 API Functions

3.1 FlashErase Function
This function allows the user to erase any Flash block within the MCU including the near area memory (below address 0xFFFF).

`int FlashErase( int block);`

Return Value
Returns the outcome of the erase operation: 1 if successful and 0 if not successful.

Parameters
`block`

Specifies the block to erase. The blocks are numbered in the same fashion as they are in the device specifications; the highest address block is labeled "0". Furthermore, the near area Flash blocks are labeled in succession after the User Area blocks (i.e. "4"&"5" for the M16C/26 and "11" for the M16C/62P).
3.2 FlashWrite Function

This function allows data to be written into Flash. The number of bytes to write MUST be an even number because the flash controller has to write a WORD (16 bits) at a time. The flash address MUST also be an even number as well because the flash controller needs to write WORDS to even addresses only.

```
int FlashWrite(unsigned long flash_addr, far unsigned char *buffer_addr, unsigned int bytes);
```

**Return Value**

Returns the outcome of the write operation: 1 if successful and 0 if not successful.

**Parameters**

`flash_addr`

This is the address of the Flash area to write to. This must be an even address in Flash.

`buffer_addr`

This is the address of the data buffer containing the data to write to Flash. This address can be either a location in RAM or Flash.

`Bytes`

The number of bytes contained in the data buffer. This must always be an even number because the MCU can only program a WORD of data at a time. This parameter represents the number of “bytes” instead of “words” in order to avoid confusion of how much data is being passed.
5.0 Software Code

5.1 Main Program

The following is an example of using the API in order to erase and program a Flash block in a M16C/26 device.

```c
#include "flash-262-ew1.h"

unsigned char data_buffer[256];

/* We have predefined a section in the sect30 file to hold some */
/* const data at a fixed location (0xF000). When the program is loaded */
/* into KD30, we will see this data has programmed into Flash at address */
/* 0xF000. We will use this to verify that the Erase function works. */
#pragma SECTION rom fixed
/* This will pre-fill our 256 byte area */
const far long watch_here[8][8] =
{0xAABBCCDD,0xAABBCCDD,0xAABBCCDD,0xAABBCCDD,
 0xAABBCCDD,0xAABBCCDD,0xAABBCCDD,0xAABBCCDD};

void main() {
    int i;
    int ok;

    /* Fill our data buffer */
    for(i=0;i<256;i++)
        data_buffer[i] = i;

    /* Place a breakpoint on the following line in order to view the flash */
    /* contents at address 0xF000 before it is erased. You can use the Memory */
    /* Window in KD30 to do this. */
    i = 1;
    /* PLACE BREAKPOINT ON THIS LINE */
    /* View address 0xF000 */

    ok = FlashErase( 5 ); // Erase Block 5 (0xF000 - 0xF7FF)
    if( !ok ) // Note that interrupts are disabled during this function
        while(1);
        /* ERROR ERASING */
```
i = 2;       /* PLACE BREAKPOINT ON THIS LINE */
/* View address 0xF000, should be all FF */

ok = FlashWrite( 0xF000, // Flash address write to (must be on a 256-byte page boundry)
data_buffer, // Address of buffer containing data to write
256);       // Number of byte in buffer
            // Note that interrupts are disabled during this

// function
if( !ok )
    while(1);       /* ERROR PROGRAMMING */

i = 3;       /* PLACE BREAKPOINT ON THIS LINE */
/* View address 0xF000, should look like our data_buffer */

while(1);    /* The End */
}
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